Technical Data Sheet

DPDT Ramses SMA 18GHz Latching Self-cut-off 28Vdc TTL Diodes
Pins Terminals with bracket

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RF CHARACTERISTICS

Frequency range : **0 - 18 GHz**
Impedance : **50 Ohms**

Frequency (GHz)	DC - 3	3 - 8	8 - 12.4	12.4 - 18
VSWR max	1.20	1.30	1.40	1.50
Insertion loss max	0.20 dB	0.30 dB	0.40 dB	0.50 dB
Isolation min	80 dB	70 dB	65 dB	60 dB
Average power (*)	240 W	150 W	120 W	100 W

ELECTRICAL CHARACTERISTICS

Actuator : **LATCHING**
Nominal current ** : **125 mA**
Actuator voltage (Vcc) : **28V (24 to 30V)**
Terminals : **solder pins (250°C max. / 30 sec.)**
Self cut-off time : **40 ms < CT < 120 ms**
TTL inputs (E) - High level : **2.2 to 5.5 V / 800µA at 5.5 V**
- Low level : **0 to 0.8 V / 20µA at 0.8 V**

MECHANICAL CHARACTERISTICS

Connectors : **SMA female per MIL-C 39012**
Life : **2.5 million cycles**
Switching Time*** : **< 15 ms**
Construction : **Splashproof**
Weight : **< 100 g**

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : **-40°C to +85°C**
Storage temperature range : **-55°C to +85°C**

(* Average power at 25°C per RF Path)
(** At 25° C ±10%)
(*** Nominal voltage ; 25° C)

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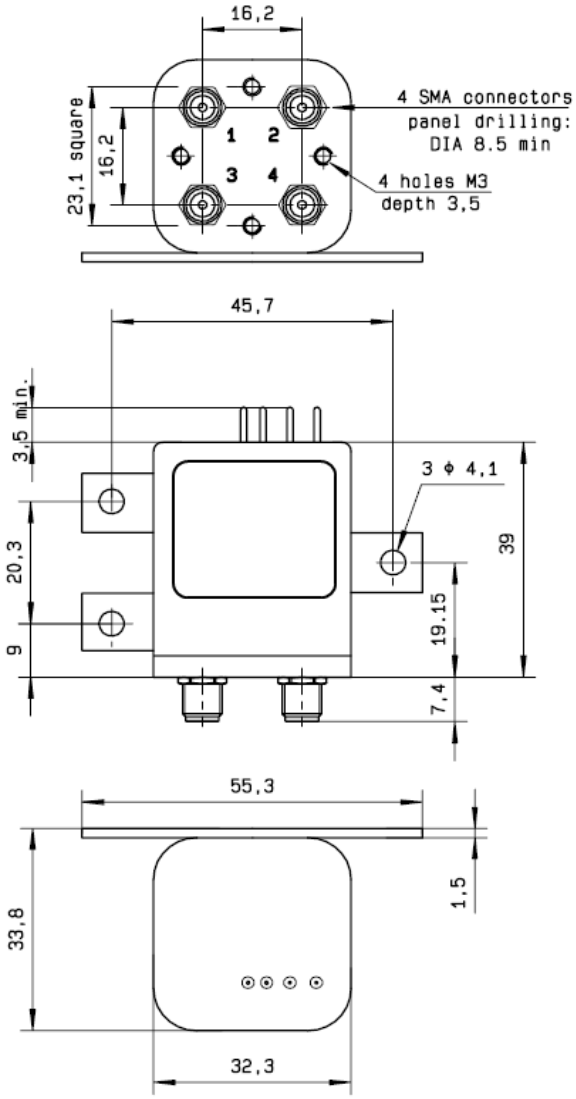
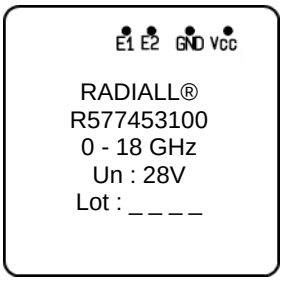
DRAWING

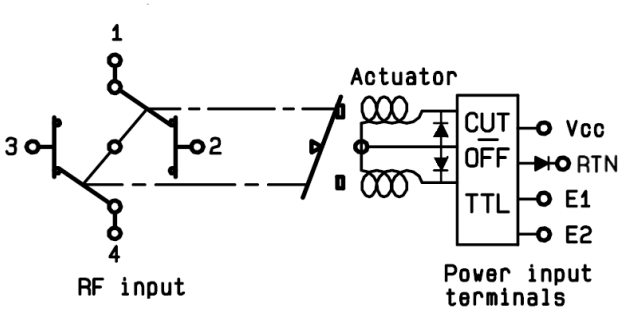


LABEL



General tolerances : ±0.5 mm

SCHEMATIC DIAGRAM



TTL input	RF Continuity
E1=1 / E2=0	1 ↔ 3 / 2 ↔ 4
E1=0 / E2=1	1 ↔ 2 / 3 ↔ 4
E1=0 / E2=0	Memory
E1=1 / E2=1	Forbidden